NSN 5961-01-460-2991

Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|--|
| Plastic |
| Overall Length: |
| Between 0.360 inches and 0.375 inches |
| Terminal Length: |
| 1.100 inches |
| Overall Diameter: |
| Between 0.190 inches and 0.205 inches |
| Function For Which Designed: |
| Transient suppressor |
| End Application: |
| E/i fscm 14552 |
| Mounting Method: |
| Terminal |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 13.6 reverse voltage, peak and 16.8 breakdown voltage, dc |
| Current Rating Per Characteristic: |
| 200.00 amperes forward current, average preset and 67.00 amperes source cutoff current universal |
| Special Features: |
| 1500w peak pulse power; junction pattern arrangement: pn |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
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